

IMP2014/15, IMP2185

POWER MANAGEMENT

60mA/110mA/160mA Super Low Dropout CMOS Regulators with Battery Life Extending Shutdown Mode

The IMP2014, IMP2015 and IMP2185 high performance CMOS low dropout voltage regulators offer superior dropout voltage performance and load regulation characteristics as compared to the pin compatible TC1014/1015/1185 devices offered by TelCom Semiconductor. Dropout voltage performance has been improved by up to 40%.

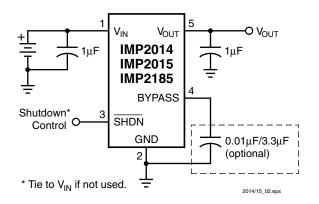
Load regulation and power supply PSRR have been optimized. Load regulation is typically 0.32% and PSRR is 53dB at 1kHz.

A logic input controlled shutdown mode extends system battery life by reducing quiescent current to $0.2\mu A$ maximum. The shutdown mode can be initiated by a system microcontroller.

The regulators were designed with ease of use and stability in mind. Stability is guaranteed for $0.47\mu F$ and greater load capacitors with an ESR up to 5Ω . Ceramic or tantalum capacitors can be used.

Three devices with different guaranteed output current specifications are available: IMP2014 (60mA), IMP2015 (110mA) and IMP2185 (160mA). Each device has output voltage options of 2.5V, 2.7V, 2.85V, 3.0V, 3.3V, 3.6V and 4.0V.

Typical Application



Key Features

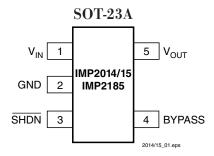
- ▶ Pin Compatible with TelCom TC1014/1015/1185
- Lower Dropout Voltage for Long Battery Life
 - IMP2014: 70mV vs. TelCom TC1014 120mV
 - IMP2015: 160mV vs. TelCom TC1015 250mV
 - IMP2185: 250mV vs. TelCom TC1185 400mV
- ◆ Power Saving Shutdown Mode
 - 0.2µA shutdown current
- ♦ Superior Load Regulation
 - **0.32**%
- **♦** Long Battery Life
 - 33µA no load ground current
- ◆ Accurate Output Voltage
 - ± 2.5% over temperature
- ♦ Low Drift Output: 40ppm/°C
- **♦** Guaranteed Minimum Output Current
 - IMP2014: 60mA
 - IMP2015: 110mA
 - IMP2185: 160mA
- Over-Current and Over-Temperature Protection
- Reference Bypass Input for Low-noise and Improved PSRR
- ◆ Compact SOT-23A-5 Package

Applications

- Pagers
- ◆ Cellular/GSM/PHS Phones
- ◆ Instrumentation
- Wireless Terminals
- Battery Powered Systems
- Medical Instruments
- Linear Post-Regulators



Pin Configuration



Pin Descriptions

Pin Number	Name	Function
1	V _{IN}	Unregulated supply input.
2	GND	Ground terminal.
3	SHDN	Shutdown control input. A shutdown mode is entered when SHDN is a logic LOW. During shutdown the output voltage falls to 0V and quiescent current drops to 2.0μA.
4	BYPASS	Reference bypass input. A capacitor connected from the BYPASS pin to ground reduces the noise present on the internal reference and enhances PSRR
5	V _{OUT}	Output voltage

2014/15_t01.eps

Ordering Information

		Output Voltage	Output Current	Shutdown	Adjust	OKAY Flag	Reference	Package Marking			
Part Number*	Package	(V)	(mA)	Pin	Pin	Output	Bypass Pin	A	В	С	D
IMP2014-2.5JUK/T	SOT23A-5	2.5	60	•			•	М	Α	Х	х
IMP2014-2.7JUK/T	SOT23A-5	2.7	60	•			•	М	В	Х	х
IMP2014-2.85JUK/T	SOT23A-5	2.85	60	•			•	М	С	Х	х
IMP2014-3.0JUK/T	SOT23A-5	3.0	60	•			•	М	D	Х	х
IMP2014-3.3JUK/T	SOT23A-5	3.3	60	•			•	М	Е	Х	х
IMP2014-3.6JUK/T	SOT23A-5	3.6	60	•			•	М	F	Х	х
IMP2014-4.0JUK/T	SOT23A-5	4.0	60	•			•	М	G	Х	х
IMP2015-2.5JUK/T	SOT23A-5	2.5	110	•			•	0	Α	Х	х
IMP2015-2.7JUK/T	SOT23A-5	2.7	110	•			•	0	В	Х	Х
IMP2015-2.85JUK/T	SOT23A-5	2.85	110	•			•	0	С	Х	х
IMP2015-3.0JUK/T	SOT23A-5	3.0	110	•			•	0	D	Х	х
IMP2015-3.3JUK/T	SOT23A-5	3.3	110	•			•	0	Е	Х	Х
IMP2015-3.6JUK/T	SOT23A-5	3.6	110	•			•	0	F	Х	х
IMP2015-4.0JUK/T	SOT23A-5	4.0	110	•			•	0	G	Х	х
IMP2185-2.5JUK/T	SOT23A-5	2.5	160	•			•	Χ	Α	Х	х
IMP2185-2.7JUK/T	SOT23A-5	2.7	160	•			•	Χ	В	Х	х
IMP2185-2.85JUK/T	SOT23A-5	2.85	160	•			•	Χ	С	Х	х
IMP2185-3.0JUK/T	SOT23A-5	3.0	160	•			•	Χ	D	Х	х
IMP2185-3.3JUK/T	SOT23A-5	3.3	160	•			•	Χ	Е	Х	х
IMP2185-3.6JUK/T	SOT23A-5	3.6	160	•			•	Χ	F	Х	х
IMP2185-4.0JUK/T	SOT23A-5	4.0	160	•			•	Χ	G	Х	х

xx = Date Code * /T indicates Tape and Reel

2014/15_t03.eps



Absolute Maximum Ratings

Input Voltage	7V
Output Voltage	$-0.3V$ to $V_{IN} + 0.3V$
Maximum Voltage on Any Pin	$-0.3V$ to $(V_{IN} + 0.3V)$
Shutdown Voltage (SHDN)	$\overline{SHDN} \le V_{IN} + 0.3V$

These are stress ratings only and functional operation is not implied. Exposure to absolute maximum ratings for prolonged time periods may affect device reliability. All voltages are with respect to ground.

Operating Junction Temperature Range $\dots -40^{\circ}\text{C} < T_J < 125^{\circ}\text{C}$
Storage Temperature65°C to 150°C
Power Dissipation Internally limited

Note: T_I = Junction Temperature, T_A = Ambient Temperature

Electrical Characteristics

 $V_{IN} = V_{OUT} + 1V$, $I_L = 100\mu A$, $C_L = 1\mu F$, $\overline{SHDN} > V_{IH}$, $T_A = 25$ °C, unless otherwise noted. **Bold/blue** specifications apply for junction temperature range -40°C $< T_J < 125$ °C.

Parameter	Symbol	Conditions	Min	Тур	Max	Units
Input Voltage Range	V _{IN}	0°C < T _J < 125°C			6.50	V
		-40°C < T _J < 125°C			6.50	
Maximum Output Current	I _{OMAX}	IMP2014	60			mA
		IMP2015	110			
		IMP2185	160			
Fixed Output Voltage	V _{OUT}	Note 1	V _R - 2.5%	V _R ± 0.5%	V _R + 2.5%	V
Dropout Voltage (Note 2)	V _{IN} - V _O	$I_L = 100 \mu A$		1		mV
		I _L = 20mA		17	23	
		I _L = 50mA		60	70	
		I _L = 100mA (IMP2015, IMP2185)		90	160	
		I _L = 150mA (IMP2185)		143	250	
Quiescent Current (Ground Current)		No load		33	50	μА
Shutdown Supply Current	I _{INSD}	$\overline{SHDN} = 0V$ $T_{J} \le 25^{\circ}C$		0.2	2	μА
Output Temperature Coefficient				40		ppm/°C
Thermal Regulation				0.04		%/W
Line Regulation		$V_R + 1V \le V_{IN} \le 6V$		0.0375	0.35	%

Notes: 1. V_R is the regulated output voltage: 2.5V, 2.7V, 2.85V, 3.0V, 3.3V, 3.6V or 4.0V.

2014/15_t02a.eps

- 2. Dropout Voltage is defined as the difference between IN and OUT when V_R drops 2% below its nominal value.
- 3. Specifications which would otherwise be affected by self-heating of the die are tested at a constant die temperature by using low duty cycle pulse testing.
- 3. PSRR guaranteed by design.

© Daily Silver IMP www.ds-imp.com.cn



Electrical Characteristics

 $V_{IN} = V_{OUT} + 1V$, $I_L = 100\mu A$, $C_L = 1\mu F$, $\overline{SHDN} > V_{IH}$, $T_A = 25$ °C, unless otherwise noted. **Bold/blue** specifications apply for junction temperature range of -40°C $< T_J < 125$ °C.

Parameter	Symbol	Conditions		Min	Тур	Max	Units
Load Regulation: IMP2014		I _L = 100μA to 50mA			0.11	0.5	%
IMP2015		I ₁ = 100μA to 100mA			0.16	1.0	
IMP2185		$I_L = 100 \mu A \text{ to } 150 \text{mA}$		0.65	1.5		
Thermal Shutdown Die Temperature					150		°C
Thermal Shutdown Hysteresis					12		°C
Ripple Rejection	PSRR	$\begin{split} V_{IN} &\geq (V_O + 1V) \pm 0.25V \\ C_O &= 3.3 \mu \text{F ceramic} \\ C_{BYPASS} &= 0.01 \mu \text{F} \end{split}$	Freq. = 1kHz		60		dB
			Freq. = 10kHz		47		
			Freq. = 1MHz		34		
Output Noise		300Hz to 50kHz No bypass capacitor $I_L = 50mA (IMP2014)$ $I_L = 100mA$			280		μV _{RMS}
		$\begin{array}{l} 300\text{Hz to } 50\text{kHz} \\ C_{\text{BYPASS}} = 0.01\mu\text{F} \\ I_{\text{L}} = 50\text{mA (IMP2014)} \\ I_{\text{L}} = 100\text{mA} \end{array}$			60		μV _{RMS}
SHDN Input HIGH Threshold		$2.5V \leq V_{IN} \leq 6.5V$		45			% of V _{IN}
SHDN Input LOW Threshold		$2.5V \leq V_{IN} \leq 6.5V$				15	% of V _{IN}
Reverse Current into V _{OUT}		$\frac{V_{(IN)} \le V_{(OUT)}}{SHDN} = HIGH = V_{IN}$			2.0		mA
		$\frac{V_{(IN)} < V_{(OUT)}}{SHDN} = LOW$			2.7		μΑ
Output Current Limit					350	600	mA

Notes: 1. V_R is the regulated output voltage: 2.5V, 2.7V, 2.85V, 3.0V, 3.3V, 3.6V or 4.0V.

2. Dropout Voltage is defined as the difference between IN and OUT when V_R drops 2% below its nominal value.

3. Specifications which would otherwise be affected by self-heating of the die are tested at a constant die temperature by using low duty cycle pulse testing.

4. PSRR guaranteed by design.

2014/15_t02b.eps

4 © Daily Silver IMP www.ds-imp.com.cn



ΔV_{IN} = 1V V_{OUT} 50mV/DIV 20μs/DIV

Figure 1. Line Transient Response

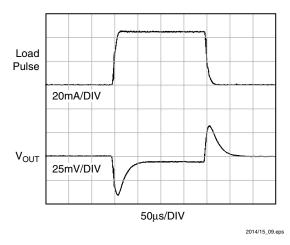


Figure 3. Load Transient Response (50mA Step)

Typical Characteristics

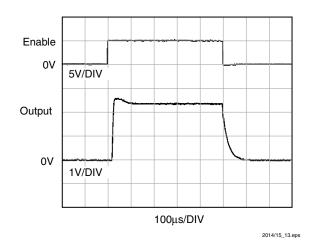


Figure 2. Enable Input Response

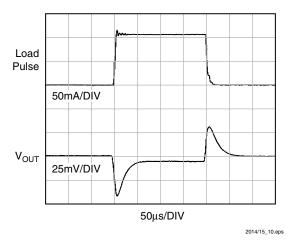


Figure 4. Load Transient Response (100mA Step)

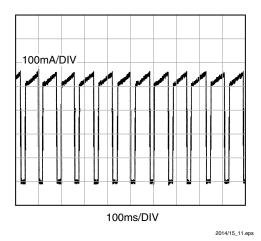


Figure 5. Output Short Circuit Response



Application Information

The IMP2014, IMP2015 and IMP2185 have been designed to offer exceptionally low dropout voltage, superior load regulation and minimum quiescent power.

Shutdown Mode

A battery-life-extending mode is available. Through the active LOW shutdown pin, SHDN, the regulator can be enabled or turned off. The regulator is shutdown (turned off) when SHDN is LOW and enabled (turned on) when SHDN is HIGH.

The shutdown signal can be supplied from a CMOS gate or from an I/O port of a microcontroller.

During shutdown, the output voltage falls to 0V and the supply current is typically only 200nA.

If the shutdown mode is not needed, SHDN should be connected directly to the regulator input voltage pin.

Output Capacitor

The IMP2014, IMP2015 and IMP2185 were designed for stable operation with a wide range of capacitor values and type. The output capacitor should be above $0.47\mu F$. A $1\mu F$ value is recommended. Ceramic or tantalum capacitors are suitable with an ESR of up to 5Ω .

Reference Voltage Bypass Capacitor

For low noise operation a $0.01\mu F$ or larger capacitor can be connected from the BYPASS pin to ground. For maximum power supply rejection/line rejection, a $3.3\mu F$ value is suggested.

The IMP2014/2015/2185 were designed so that line regulation and ripple rejection would be maximized. This was accomplished by powering the internal bandgap reference from an internal regulated source. This "pre-regulation" greatly improves power supply regulation for input voltages greater than that of the internal voltage regulator, 3.5V.

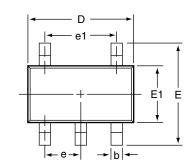
Thermal Shutdown

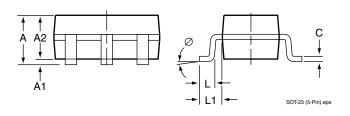
An on-chip thermal protection circuit shuts the LDO regulator off when the die temperature exceeds 150° C. There is a built in 12° C hysteresis. The regulator will remain off until the die temperature drops to approximately to 138° C.



Package Dimensions

Plastic SOT-23A (5-Pin)





		Inches	Millimeters							
	Min Nominal		Max	Min	Nominal	Max				
	Plastic SOT-23 (5-Pin)*									
Α	0.037	_	0.057	0.95	_	1.45				
A1	0.001	_	0.005	0.05	_	0.15				
A2	0.035	0.044	0.050	0.90	1.15	1.30				
b	0.011	_	0.019	0.30	_	0.50				
b1	0.011	0.015	0.017	0.30	0.40	0.45				
С	0.003		0.007	0.08	_	0.20				
c1	0.003	0.003	0.062	0.08	0.10	0.16				
D	0.109	0.113	0.117	2.80	2.90	3.00				
Е	0.101	_	0.117	2.60	_	3.00				
E1	0.058	0.062	0.066	1.50	1.60	1.70				
е		0.037 BSC		0.95 BSC						
e1		0.074 BSC		1.90 BSC						
L	0.013	0.017	0.021	0.35	0.45	0.55				
L1		0.002 REF		0.60 REF						
Ø	0°	_	8°	0°	_	8°				

^{*} JEDEC Drawing MO-178

2014/15 t04.evs



Daily Silver IMP Microelectronics Co.,Ltd 7 keda Road , Hi-Tech Park, NingBo,Zhejiang, P.R.C.

Post Code : 315040

Tel:(086)-574-87906358 Fax:(086)-574-87908866 e-mail:sales@ds-imp.com.cn Website:www.ds-imp.com.cn

2005 Daily Silver IMP Revision : A Issue Date: 08/08/05 Type: Product

^{*} Add /T to Part Number for Tape and Reel.